The Si3404 non-isolated Buck based evaluation board is a reference design for a power supply in a Power over Ethernet (PoE) Powered Device (PD) application.

This Si3404-Buck EVB maximum output level is Class 2 power ($\eta \times 6.5W$).

The Si3404-Buck EVB board is shown below. The Si3404 IC integrates an IEEE 802.03af compatible PoE interface as well as a current control based dc/dc converter.

The Si3404 PD integrates a detection circuit, classification circuit, dc/dc switch, hot-swap switch, TVS overvoltage protection, dynamic soft-start circuit, cycle-by-cycle current limit, thermal shutdown, and inrush current protection.

The switching frequency of the converter is tunable by an external resistor.

**KEY FEATURES**

- IEEE 802.03af Compatible
- Very Small Application PCB Surface
- High Efficiency
- High Integration
- Low-profile 4 x 4 mm 20-pin QFN
- Thermal Shutdown protection
- Low BOM Cost
- Transient Overvoltage Protection
1. Kit Description

The Si3404 non-isolated Buck topology based evaluation board is a reference design for power supplies in Power over Ethernet (PoE) Powered Device (PD) applications. The Si3404 device is described more completely in the data sheet and application notes. This document describes the evaluation board.

The minimum possible configurable output voltage of this evaluation board is 3.3 V.

At 3.3 V and 5 V output voltages, the EVB can be configured up to Class 2, and, at 12 V output voltage, up to Class 3 power levels.

The Si3404-Buck EVB is shown on the cover page. The schematic is shown in Figure 2.3 Si3404 Buck Non-Isolated Schematic: 5 V, Class 2 PD on page 4 and the layout in 16. Board Layout. The dc output is at connectors J13(+) and J14(–).

Boards are shipped configured to produce 5 V output voltage but can be configured for different output voltages, such as 3.3 or 12 V, for example, by changing resistor R6 and a few other components. Refer to "AN1130: Using the Si3406/Si34061/Si34062 PoE+ and Si3404 PoE PD Controller in Isolated and Non-Isolated Designs" for more information. The preconfigured Class 2 signature can also be modified, which is also described in AN1130.

The silicon type diode bridge can be replaced with Schottky type diode bridges to achieve higher overall board efficiency.

To compensate the reverse leakage of the Schottky type diode bridges at high temperature, the recommended detection resistor should be adjusted to the values listed in the following table:

**Table 1.1. Recommended Detection Resistor Values**

<table>
<thead>
<tr>
<th>External Diode Bridge</th>
<th>$R_{DET}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>Silicon Type</td>
<td>24.3 kΩ</td>
</tr>
<tr>
<td>Schottky Type</td>
<td>24.9 kΩ</td>
</tr>
</tbody>
</table>
2. Getting Started: Powering Up the Si3404-Buck Board

Ethernet data and power are applied to the board through the RJ45 connector (J1). The board itself has no Ethernet data transmission functionality, but, as a convenience, the Ethernet transformer secondary-side data is brought out to test points.

The design can be used in Gigabit (10/100/1000) systems as well by using PoE RJ45 Magjack, such as type L8BE-1G1T-BFH from Bel Fuse.

Power may be applied in the following ways:

- Using an IEEE 802.3-2015-compliant, PoE-capable PSE, such as Trendnet TPE-1020WS
- Using a laboratory power supply unit (PSU):
  - Connecting a dc source between blue/white-blue and brown/white-brown of the Ethernet cable (either polarity), (End-span) as shown below:

![Endspan Connection using Laboratory Power Supply](image1)

- Connecting a dc source between green/white-green and orange/white-orange of the Ethernet cable (either polarity), (Mid-span) as shown below:

![Midspan Connection using Laboratory Power Supply](image2)
Figure 2.3. Si3404 Buck Non-Isolated Schematic: 5 V, Class 2 PD
3. Overall EVB Efficiency

The overall efficiency measurement data of the Si3404 Buck Non-Isolated EVB board is shown below. The input voltage is 50 V, and the output voltage is 5 V.

![Efficiency Graph](image)

**Figure 3.1. Si3404 Buck Non-Isolated EVB Overall Efficiency: 50 V Input, 5 V Output, Class 2**

**Note:** The chart shows overall EVB efficiency. The voltage drop on the standard silicon diode bridge is included.
4. SIFOS PoE Compatibility Test Results

The Si3404-Buck EVB board has been successfully tested with PDA-300 Powered Device Analyzer from SIFOS Technologies. The PDA-300 Powered Device Analyzer is a single-box comprehensive solution for testing IEEE 802.3at PoE Powered Devices (PD’s).

Figure 4.1. Si3404-Buck Non-Isolated PD SIFOS PoE Compatibility Test Results
5. Feedback Loop Phase and Gain Measurement Results (Bode Plots)

The Si3404 device integrates a current mode controlled switching mode power supply controller circuit. Therefore, the application is a closed-loop system. To guarantee a stable output voltage of a power supply and to reduce the influence of input supply voltage variations and load changes on the output voltage, the feedback loop should be stable.

To verify the stability of the loop, the loop gain and loop phase shift has been measured.

![Figure 5.1. Si3404-Buck Non-Isolated PD Feedback Loop Measurement Results](image)

**Table 5.1. Measured Loop Gain and Phase Shift**

<table>
<thead>
<tr>
<th>Cursor</th>
<th>Frequency (Hz)</th>
<th>Gain</th>
<th>Phase</th>
</tr>
</thead>
<tbody>
<tr>
<td>Cursor 1 (Phase Margin)</td>
<td>1.3 kHz</td>
<td>0 dB</td>
<td>51 °</td>
</tr>
<tr>
<td>Cursor 2 (Gain Margin)</td>
<td>109 kHz</td>
<td>−33 dB</td>
<td>0 °</td>
</tr>
</tbody>
</table>
6. Step Load Transient Measurement Results

The Si3404-Buck EVB board's output has been tested with a step load function to verify the converter's output dynamic response.

| Step load: from 0.3 A to 1 A output current | Step load: from 1.0 A to 0.3 A output current |

Figure 6.1. Si3404-Buck Non-Isolated EVB Output Step Load Transient Test
7. Output Voltage Ripple

The Si3404-Buck EVB output voltage ripple has been measured in both no load and heavy load conditions.

\[
\begin{align*}
\text{No-load } V_{\text{OUT}} \text{ ripple} & = 27\text{mV} \\
\text{Heavy-load } V_{\text{OUT}} \text{ ripple} & = 27\text{mV}
\end{align*}
\]

Figure 7.1. Si3404-Buck Non-Isolated EVB Output Voltage Ripple No Load (Left) and Heavy Load (Right) Conditions
8. Soft-Start Protection

The Si3404 device has an integrated dynamic soft-start protection mechanism to avoid stressing the components by the sudden current or voltage changes associated with the initial charging of the output capacitors.

![No-load Soft-Start](image1)  ![Heavy-load Soft-Start](image2)

Figure 8.1. Si3404-Buck Non-Isolated EVB Output Voltage Soft-Start at Low Load (Left) and Heavy Load (Right) Conditions
9. Output Short Protection

The Si3404 device has an integrated output short protection mechanism, which protects the IC itself and the surrounding external components from overheating in the case of electrical short on the output.

Figure 9.1. Si3404-Buck Non-Isolated EVB Output Short Circuit Protection
10. Pulse Skipping at No-Load Condition

The Si3404 device has an integrated pulse skipping mechanism to ensure ultra-low power consumption at no load condition.

Figure 10.1. Si3404-Buck Non-Isolated EVB Pulse Skipping at No-load Condition: SWO Waveform
11. Adjustable EVB Current Limit

For additional safety, the Si3404 has an adjustable EVB current limit feature. The EVB current limit through the ISNS pin measures the voltage on \( R_{\text{SENSE}} \). When \( V_{\text{ISNS}} = -270 \text{ mV} \) (referenced to \( V_{\text{SS}} \)), the current limit circuit restarts the circuit to protect the application.

The EVB current limit for this Class 2 application can be calculated with the following formula:

\[
R_{\text{SENSE}} = 1.2\Omega
\]

\[
I_{\text{LIMIT}} = \frac{270\text{mV}}{1.2\Omega} = 225\text{mA}
\]

Equation 1. EVB Current Limit
12. Tunable Switching Frequency

The switching frequency of the oscillator is selected by choosing an external resistor ($R_{\text{FREQ}}$) connected between RFREQ and VPOS pins. The following figure will aid in choosing the $R_{\text{FREQ}}$ value to achieve the desired switching frequency.

![Figure 12.1. Switching Frequency vs $R_{\text{FREQ}}$](image)

The selected switching frequency for this application is 220 kHz, which is achieved by setting the $R_{\text{FREQ}}$ resistor to 88.7 kΩ.
13. Discontinuous (DCM) and Continuous (CCM) Current Modes

At low-load the converter works in discontinuous current mode (DCM), at heavy load the converter runs in continuous current mode (CCM). At low-load the SWO voltage waveform has a ringing waveform, which is typical for a DCM operation.

Figure 13.1. Si3404-Buck Non-Isolated EVB: SWO Waveform in Discontinuous Current Mode (DCM) at Low Load – Left-, and in Continuous Current Mode (CCM) at Heavy Load – Right
14. Radiated Emissions Measurement Results

Radiated emissions have been measured of the Si3404-Buck EVB board with 50 V input voltage and full load connected to the output – 6.5 W.

As shown below, the Si3404-Buck EVB is fully compliant with the international EN 55022 class B emissions standard.

![Radiated EMI Measurement Process](image)

**Figure 14.1. Si3404-Buck Non-Isolated PD Radiated Emissions Measurements Results; 50 V Input, 5 V Output, 6.5 W Output Load**

14.1 Radiated EMI Measurement Process

The EVB is measured at full load with peak detection in both vertical and horizontal polarizations. This is a relatively fast process that produces a red curve (vertical polarization) and a blue curve (horizontal polarization). Next, specific frequencies are selected (red stars) for quasi-peak measurements. The board is measured again at those specific frequencies with a quasi-peak detector, which is a very slow but accurate measurement. The results of this quasi-peak detector measurement are the blue rhombuses.

The blue rhombuses represent the final result of the measurement process. To have passing results, the blue rhombuses should be below the highlighted EN 55022 Class B limit.
15. Conducted Emissions Measurement Results

The Si3404-Buck EVB board's conducted emissions have been measured, the result is shown below.

Figure 15.1. Si3404-Buck Non-Isolated PD Conducted Emissions Measurements Results; 50 V Input, 5 V Output, 6.5 W Output Load
16. Board Layout

![Top Silkscreen](image1)

![Top Layer](image2)
Figure 16.3. Internal 1 (Layer 2)

Figure 16.4. Internal 2 (Layer 3)
Figure 16.5. Bottom Layer
17. Bill of Materials

The table below is the BOM listing for the standard 5 V output evaluation board with option PoE Class 2.

**Table 17.1. Si3404BKC2 Evaluation Board Bill of Materials**

<table>
<thead>
<tr>
<th>Qty</th>
<th>Value</th>
<th>Ref</th>
<th>Rating</th>
<th>Voltage</th>
<th>Tol</th>
<th>Type</th>
<th>PCB Footprint</th>
<th>Part Number</th>
<th>Mfr</th>
</tr>
</thead>
<tbody>
<tr>
<td>2</td>
<td>C1, C3</td>
<td>1 µF</td>
<td>100 V</td>
<td>±10%</td>
<td>X7R</td>
<td>C1210</td>
<td>C1210X7R101-105K</td>
<td>Venkel</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>C2</td>
<td>12 µF</td>
<td>100 V</td>
<td>±20%</td>
<td>Alum_Elec</td>
<td>C2.5X6.3MM-RAD</td>
<td>EEUF2A120</td>
<td>Panasonic</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>C22</td>
<td>0.1 µF</td>
<td>16 V</td>
<td>±10%</td>
<td>X7R</td>
<td>C0805</td>
<td>C0805X7R160-104K</td>
<td>Venkel</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>C5</td>
<td>560 µF</td>
<td>6.3 V</td>
<td>±20%</td>
<td>Alum_Elec</td>
<td>C3.5X8MM-RAD</td>
<td>EEUFM0J561</td>
<td>Panasonic</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>C7</td>
<td>1 nF</td>
<td>50 V</td>
<td>±1%</td>
<td>C0G</td>
<td>C0805</td>
<td>C0805C0G500-102F</td>
<td>Venkel</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>C8</td>
<td>0.1 µF</td>
<td>100 V</td>
<td>±10%</td>
<td>X7R</td>
<td>C0805</td>
<td>C0805X7R101-104K</td>
<td>Venkel</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>C9</td>
<td>22 µF</td>
<td>6.3 V</td>
<td>±20%</td>
<td>X5R</td>
<td>C0805</td>
<td>C0805X5R6R3-226M</td>
<td>Venkel</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>D1</td>
<td>PDS5100</td>
<td>5 A</td>
<td>100 V</td>
<td>Single</td>
<td>DO-214AC</td>
<td>S1B</td>
<td>Diodes Inc.</td>
<td></td>
</tr>
<tr>
<td>8</td>
<td>D12, D13, D14, D15, D16, D17, D18, D19</td>
<td>S1B</td>
<td>1.0 A</td>
<td>100 V</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>FB1</td>
<td>30 Ω</td>
<td>3000 mA</td>
<td>SMT</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>MuRata</td>
</tr>
<tr>
<td>1</td>
<td>J1</td>
<td>RJ-45</td>
<td>Recptacle</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>Bel</td>
</tr>
<tr>
<td>2</td>
<td>J13, J14</td>
<td>BND_POST</td>
<td>15 A</td>
<td>BANANA</td>
<td>BANANA-JACK</td>
<td>101</td>
<td>ABBATRON HH SMITH</td>
<td></td>
<td></td>
</tr>
<tr>
<td>2</td>
<td>L1, L2</td>
<td>742792040</td>
<td>2000 mA</td>
<td>700 Ohm @150 MHz</td>
<td>SMT</td>
<td>L0805</td>
<td>742792040</td>
<td>Wurth</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>L3</td>
<td>33 µH</td>
<td>5.2 A</td>
<td>±20%</td>
<td>Shielded</td>
<td>IND-SPD</td>
<td>MSS1278-333ML</td>
<td>Coilcraft</td>
<td></td>
</tr>
<tr>
<td>2</td>
<td>R1, R2</td>
<td>330 Ω</td>
<td>1/10 W</td>
<td>±1%</td>
<td>Thick-Film</td>
<td>R0805</td>
<td>CR0805-10W-3300F</td>
<td>Venkel</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>R10</td>
<td>75 Ω</td>
<td>1/10 W</td>
<td>±1%</td>
<td>Thick-Film</td>
<td>R0805</td>
<td>CR0805-10W-75R0F</td>
<td>Venkel</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>R11</td>
<td>24.3 kΩ</td>
<td>1/8 W</td>
<td>±1%</td>
<td>Thick-Film</td>
<td>R0805</td>
<td>CRCW080524K3FKE A</td>
<td>vishay</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>R13</td>
<td>1.2 Ω</td>
<td>1/10 W</td>
<td>±5%</td>
<td>Thick-Film</td>
<td>R0805</td>
<td>CR0805-10W-1R2J</td>
<td>Venkel</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>R5</td>
<td>3.24 kΩ</td>
<td>1/8 W</td>
<td>±1%</td>
<td>Thick-Film</td>
<td>R0805</td>
<td>CRCW08053K24FKE A</td>
<td>Vishay</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>R6</td>
<td>9.09 kΩ</td>
<td>1/10 W</td>
<td>±0.5%</td>
<td>±25PPM</td>
<td>R0805</td>
<td>RR1220P-9091-D-M</td>
<td>Susumu</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>R7</td>
<td>47 kΩ</td>
<td>1/10 W</td>
<td>±5%</td>
<td>Thick-Film</td>
<td>R0805</td>
<td>CR0805-10W-473J</td>
<td>Venkel</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>R8</td>
<td>88.7 kΩ</td>
<td>1/8 W</td>
<td>±1%</td>
<td>Thick-Film</td>
<td>R0805</td>
<td>CRCW080588K7FKE A</td>
<td>Vishay</td>
<td></td>
</tr>
<tr>
<td>Qty</td>
<td>Value</td>
<td>Ref</td>
<td>Rating</td>
<td>Voltage</td>
<td>Tol</td>
<td>Type</td>
<td>PCB Footprint</td>
<td>Mfr Part Number</td>
<td>Mfr</td>
</tr>
<tr>
<td>-----</td>
<td>----------------</td>
<td>-------</td>
<td>--------</td>
<td>---------</td>
<td>------</td>
<td>------</td>
<td>---------------</td>
<td>-----------------</td>
<td>-----------</td>
</tr>
<tr>
<td>4</td>
<td>SO1, SO2, SO3, SO4</td>
<td>Standoff</td>
<td></td>
<td></td>
<td>HDW</td>
<td></td>
<td></td>
<td></td>
<td>2397</td>
</tr>
<tr>
<td></td>
<td>U1</td>
<td>Si3404</td>
<td>120 V</td>
<td>PD</td>
<td>QFN20N4X4P0.5</td>
<td>Si3404-A-GM</td>
<td>SiLabs</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

**Not-Installed Components**

<table>
<thead>
<tr>
<th>Qty</th>
<th>Value</th>
<th>Ref</th>
<th>Rating</th>
<th>Voltage</th>
<th>Tol</th>
<th>Type</th>
<th>PCB Footprint</th>
<th>Mfr Part Number</th>
<th>Mfr</th>
</tr>
</thead>
<tbody>
<tr>
<td>9</td>
<td>C12, C13, C14, C15, C16, C17, C18, C19, C33</td>
<td>1 nF</td>
<td>100 V</td>
<td>±10%</td>
<td>X7R</td>
<td>C0603</td>
<td></td>
<td>C0603X7R101-102K</td>
<td>Venkel</td>
</tr>
<tr>
<td>1</td>
<td>C6</td>
<td>3.3 nF</td>
<td>16 V</td>
<td>±10%</td>
<td>X7R</td>
<td>C0805</td>
<td></td>
<td>C0805X7R160-332K</td>
<td>Venkel</td>
</tr>
<tr>
<td>1</td>
<td>R9</td>
<td>100</td>
<td>½ W</td>
<td>±1%</td>
<td>Thick-Film</td>
<td>R1210</td>
<td></td>
<td>CR1210-2W-1000F</td>
<td>Venkel</td>
</tr>
<tr>
<td>10</td>
<td>TP1, TP2, TP3, TP4, TP5, TP6, TP7, TP8, TP9, TP10</td>
<td>Black</td>
<td>LOOP</td>
<td>TESTPOINT</td>
<td>5001</td>
<td></td>
<td></td>
<td></td>
<td>Keystone</td>
</tr>
</tbody>
</table>
Although the EVB design is pre-configured as a Class 2 PD with 5 V output, the schematics and layouts can easily be adapted to meet a wide variety of common output voltages and power levels.

The complete EVB design databases for the standard 5 V/Class 2 configuration are located at www.silabs.com/PoE link. Silicon Labs strongly recommends using these EVB schematics and layout files as a starting point to ensure robust performance and avoid common mistakes in the schematic capture and PCB layout processes.

Below is a recommended design checklist that can assist in trouble-free development of robust PD designs.

Refer also to the Si3404-BUCK data sheet and AN1130 when using the following checklist.

1. Design Planning Checklist:
   a. Determine if your design requires an isolated or non-isolated topology. For more information, see AN1130.
   b. Silicon Labs strongly recommends using the EVB schematics and layout files as a starting point as you begin integrating the Si3404-BUCK into your system design process.
   c. Determine your load's power requirements (i.e., V\text{OUT} and I\text{OUT} consumed by the PD, including the typical expected transient surge conditions). In general, to achieve the highest overall efficiency performance of the Si3404-BUCK, choose the highest output voltage option used in your PD and then post regulate to the lower supply rails, if necessary.
   d. Based on your required PD power level, select the appropriate class resistor R\text{CLASS} value by referring to AN1130.

2. General Design Checklist:
   a. ESD caps (C12–C19 in Figure 2.3 Si3404 Buck Non-Isolated Schematic: 5 V, Class 2 PD on page 4) are strongly recommended for designs where system-level ESD (IEC6100-4-2) must provide >15 kV tolerance.
   b. If your design uses an AUX supply, be sure to include a 3 Ω surge limiting resistor in series with the AUX supply for hot insertion. Refer to AN1130 when AUX supply is 48 V.
   c. Non-standard PoE injectors turns on the PD without detection and classification phases. In most cases, dV/dt is not controlled and could violate IEEE requirements. To ensure robustness with those injectors, please include a 2 x 3 Ω resistors in series with L1 and L2.
   d. Silicon Labs recommends the inclusion of a minimum load (250 mW) to avoid the PSE port being disconnected by the PSE. If your load is not at least 250 mW, add a resistor load to dissipate at least 250 mW.

3. Layout Guidelines:
   a. Make sure VNEG pin of the Si3404 is connected to the backside of the QFN package with an adequate thermal plane, as noted in the data sheet and AN1130.
   b. Keep the trace length from SWO to VSS as short as possible. Make all of the power (high current) traces as short, direct, and thick as possible. It is a good practice on a standard PCB board to make the traces an absolute minimum of 15 mils (0.381 mm) per ampere.
   c. Usually, one standard via handles 200 mA of current. If the trace needs to conduct a significant amount of current from one plane to the other, use multiple vias.
   d. Keep the circular area of the loop from the Switcher FET output to the inductor or transformer and returning from the input filter capacitors (C1–C3) to VSS as small a diameter as possible. Also, minimize the circular area of the loop from the output of the inductor or transformer to the Schottky diode and returning through the first stage output filter capacitor back to the inductor or transformer as small as possible. If possible, keep the direction of current flow in these two loops the same.
   e. Keep the high power traces as short as possible.
   f. Keep the feedback and loop stability components as far from the transformer/inductor and noisy power traces as possible.
   g. If the outputs have a ground plane or positive output plane, do not connect the high current carrying components and the filter capacitors through the plane. Connect them together, and then connect to the plane at a single point.

To help ensure first-pass success, contact our customer support by submitting a help ticket and uploading your schematics and layout files for review.
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